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The study of high power couplers for CIADS*

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ABSTRACT

High power couplers with high operation reliability are needed for the superconducting cavities used in the Linac of CiADS project at IMP. This poster will report two works on high power coupler. The DC bias structure of the coupler was optimized to suppress the multipacting effect, where the series resistors were introduced to the wire of the DC bias to reduce the field propagating along the wire of DC bias. For the purpose of significantly decreasing the power needed to condition the coupler, a new RF conditioning scheme was developed, in which the couplers served as a standing wave resonator, and the position of the crests and troughs of the wave were tunable. The details of the design mentioned above will be depicted.

The field propagating along the wire of DC bias

Reduction of the field along the DC bias wire

DC bias was used to suppress multipacting in input couplers

The common method to block the field along the wire was

- Field in coupler can penetrate the DC bias capacitor and then propagating along the wire of DC bias.
- The field would affect the transmission performance of the coaxial coupler and can interfere the DC bias power supply.
- The generation of the field can be analyzed by The Principle of Schelkunoff



- introducing an inductance or ferrite choke to the wire, which was not always effective.
- Series resistors were found to block the field along the wire successfully.
- The S parameter and the RF loss of the wire with series resistors were related with the resistors' resistance.



- Fig.2 S21 parameter and RF loss of the resistors
- with series resistors The principle of the resistor's blocking effect was analyzed $H_{dI}^{\text{total}}(\rho, z) = H_{dI}^{\text{inc}}(\rho, z) + H_{dI}^{\text{scatt}}(\rho, z)$

The standing wave resonant conditioning scheme

- > To reduce the power needed for the coupler conditioning, the resonant ring was the traditional choice, the power gain of which can hardly exceed 35-40.
- > To further reduce the conditioning power, a pair of couplers were changed into a $n^*\lambda/2$ resonantor as shown in Fig6.
- > The movable short boards were connected to the tail of each coupler, to move the position of the crests and troughs of the resonant field between the boards.





*<SCATTERING ANALYSIS FROM A GAP IN THE Fig.4 The coaxial line with a gap in the inner conductor INNER CONDUCTOR OF A COAXIAL LINE>

The final blocking effect with series resistor was measured ——— the display voltage of the structure without resistors The display voltage of —— the display voltage without interference the display voltage of the structure with resistors power 650 DC bias 600 Epk of HWR cavity [MV/m] Fig.5 The display voltage of DC bias power supply at different status

The analysis of the new conditioning scheme

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